



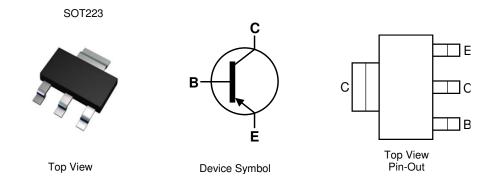
300V PNP HIGH VOLTAGE TRANSISTOR IN SOT223

Features

- BV_{CEO} > -300V
- I_C = -0.5A Continuous Current
- I_{CM} = -1A Peak Pulse Current
- Complementary NPN Type: FZT657
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/guality/product-definitions/</u>

Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208⁽³⁾
- Weight: 0.112 grams (Approximate)



Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT757TA	Standard	FZT757	7	12	1,000

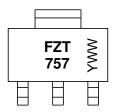
Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4.For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





FZT 757 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 2 = 2022) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-300	V
Collector-Emitter Voltage	V _{CEO}	-300	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-0.5	A
Peak Pulse Current	I _{CM}	-1	A

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		3.0	
Power Dissipation	(Note 6)		2.0	w
Fower Dissipation	(Note 7)	PD	1.6	vv
	(Note 8)		1.2	
	(Note 5)		41.7	
Thermal Resistance. Junction to Ambient	(Note 6)		62.5	°C/W
mermai nesistance, sunction to Ambient	(Note 7)	R _{0JA}	78.1	0/11
	(Note 8)		104	
Thermal Resistance, Junction to Leads	(Note 9)	R _{ejl}	12.9	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C	

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.

7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.

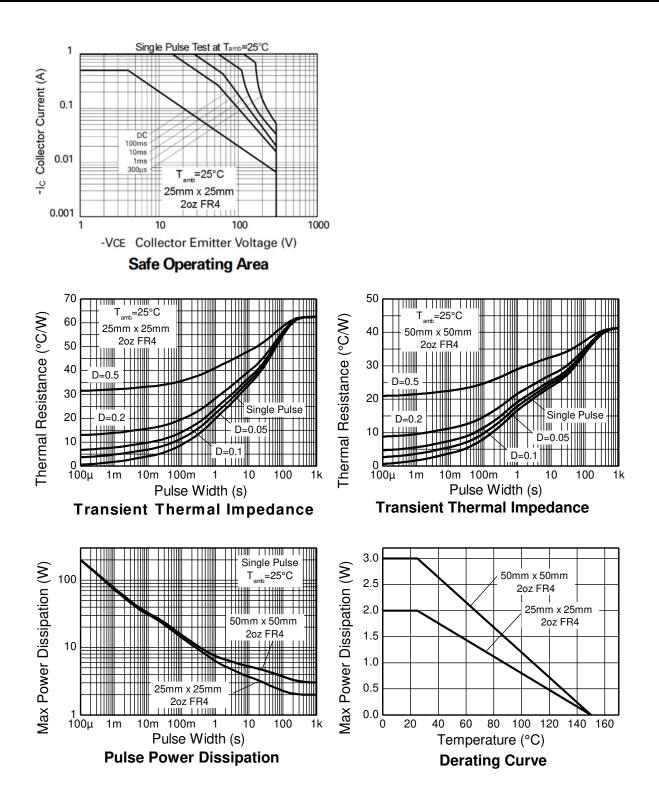
8. Same as Note 5, except the device is mounted on minimum recommended pad layout.

Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



FZT757

Thermal Characteristics and Derating Information





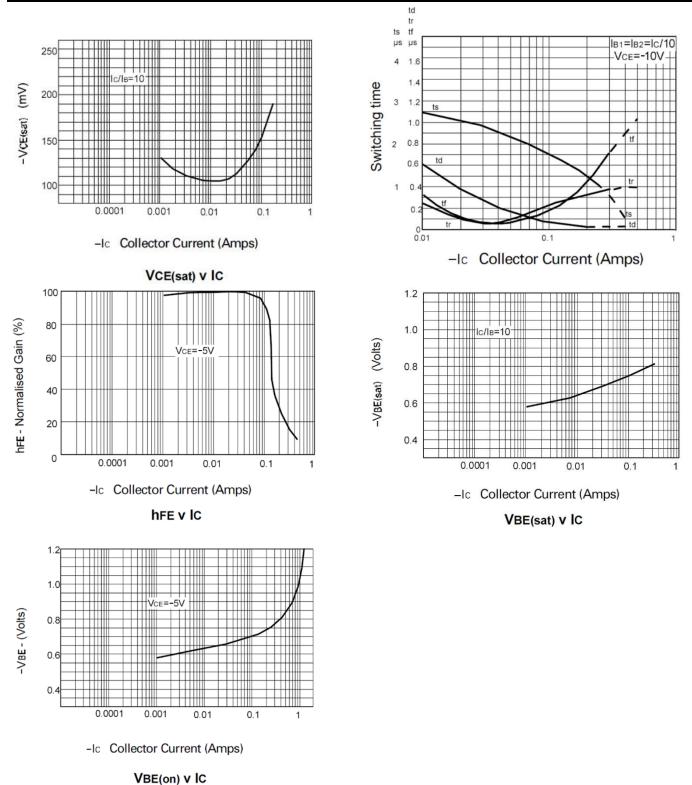
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-300	-	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	-300	-	_	V	$I_{C} = -10 \text{mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	—	—	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	-	-1	-100	nA	V _{CB} = -200V
Emitter Cut-Off Current	I _{EBO}	_	-1	-20	nA	V _{EB} = -5.6V
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(sat)}	-	-	-0.5	V	$I_{\rm C} = -100 {\rm mA}, I_{\rm B} = -10 {\rm mA}$
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	-	-	-1.0	V	$I_{C} = -100 \text{mA}, I_{B} = -10 \text{mA}$
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(on)}	-	-	-1.0	V	$I_{C} = -100 \text{mA}, V_{CE} = -5 \text{V}$
DC Current Gain (Note 11)	h _{FE}	40	-	-		$I_{C} = -10mA, V_{CE} = -5V$
DC Current Gain (Note 11)		50	-	-	_	$I_{C} = -100 \text{mA}, V_{CE} = -5 \text{V}$
Current Gain-Bandwidth Product	f _T	30	-	-	MHz	$I_{C} = -10 \text{mA}, V_{CE} = -20 \text{V},$ f = 20MHz
Output Capacitance	C _{obo}	-	-	20	pF	V _{CB} = -20V, f = 1MHz

Note: 11. Measured under pulsed conditions. Pulse width \leq 300 µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

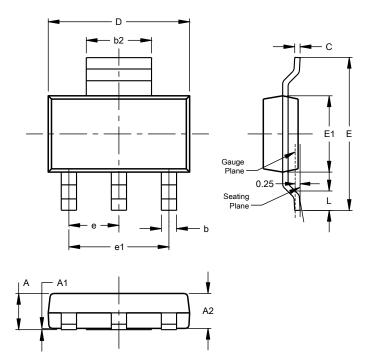




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Package Outline Dimensions

Please see https://www.diodes.com/design/support/packaging/ for the latest version.

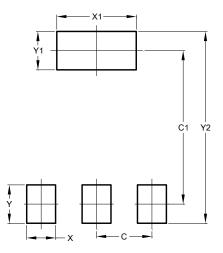


SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
С	0.20	0.32			
D	6.30	6.70			
E	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see https://www.diodes.com/design/support/packaging/ for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



FZT757

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